



*KITP Workshop on Friction, Fracture and Earthquake Physics
Santa Barbara, CA*

Friction and Adhesion in MEMS

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Sandia is a multiprogram laboratory operated by Sandia Corporation, a Lockheed Martin Company,
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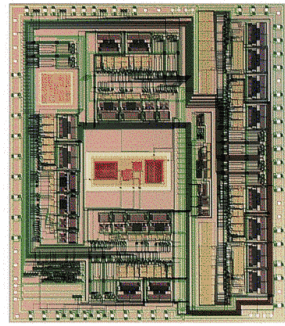
Acknowledgments

- Sandia
 - Alex Corwin
- U. Colorado Boulder
 - Frank DeRio
 - Martin Dunn
- U. Wisconsin
 - Rob Carpick



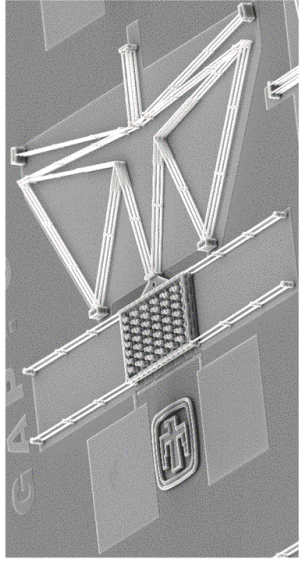
With polysilicon MEMS we can reliably accomplish electromechanical and optical functions

Integrated inertial sensor



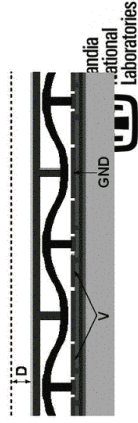
- thousands of devices simultaneously
- no assembly required
- hundreds of device concepts explored

High performance comb drive with mechanical amplifier



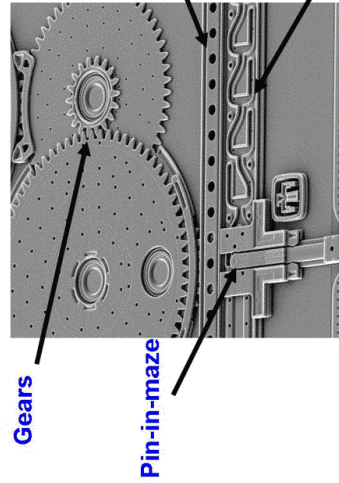
slide 3

Polychromator :
programmable
diffraction grating

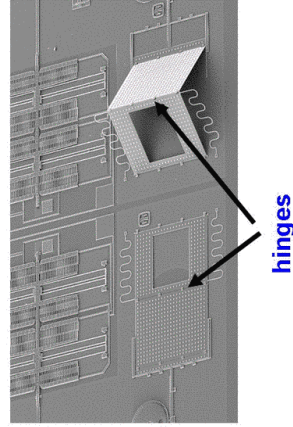


Allowing contact between MEMS surfaces significantly broadens the design space

Complex Mechanical Logic



Pop-up Mirrors



but ...
static friction can dominate the forces required
dynamic friction can dominate energy loss
adhesion, friction and wear become the most important
failure mechanisms of contacting MEMS

slide 4

MEMS – surface micromachining implementation

Design

A series of structural and sacrificial layers are deposited

Ground plane layer (Poly 0)
4 structural levels (Poly 1 - Poly 4)

Chemical Mechanical Planarization (CMP)
1 μm design rule

Create freestanding thin film structures by “release” process

Sniegowski & de Boer, Annu. Rev. Mater. Sci. (2000)

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slide 5

Taking advantage of friction, we developed a high-performance actuator

- 40 nanometer step size
- moves ± 100 μm
- high force actuator
- requires traction (friction) to move

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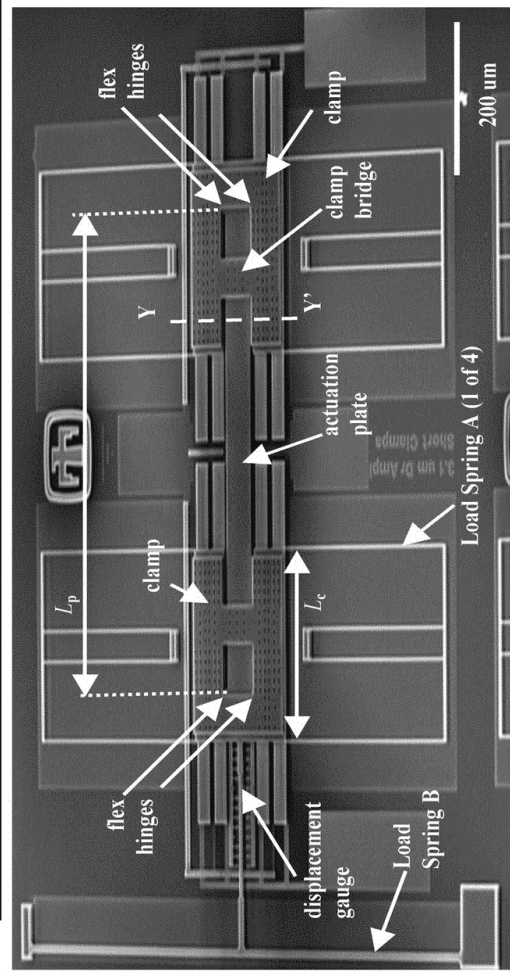


$$F_{\max} \sim 2Ewt \left(\frac{A}{L_p} \right)^2 \approx 1 \text{ mN}$$

large tangential force range

slide 6

Nanotractor - SEM

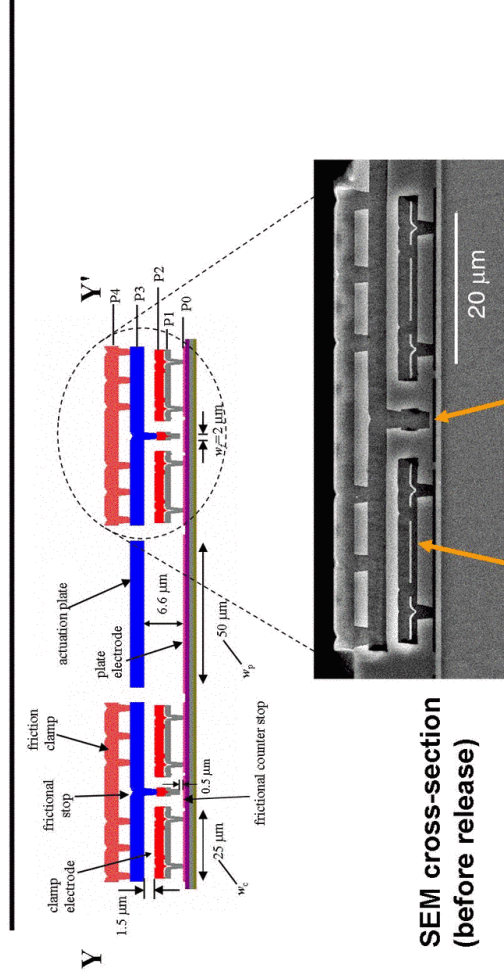


M. P. de Boer, D. L. Luck, W. R. Ashurst et al.
 "High Performance Surface-Micromachined Inchworm Actuator"
 J. MicroElectroMechanical Systems, Feb. 2004



slide 7

Nanotractor – clamp cross section

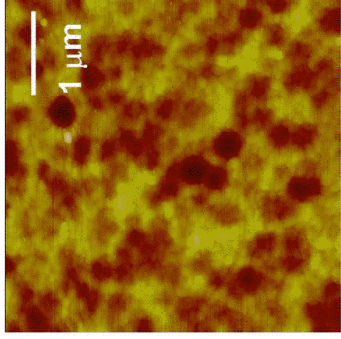
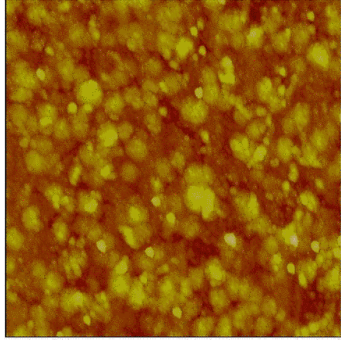


Normal force is applied electrostatically and borne mechanically
 We can apply normal force from 1 μN to 10 mN with this arrangement



slide 8

Surface contact is an aggregate of asperities



bottom counterface
(top of P0, 8 nm rms)

top counterface
(bottom of P12, 5 nm rms)

Rough surface contact mechanics considerations ...

asperity radius of curvature $R \sim 20$ to 500 nm (typically ~ 50 nm)
 rms roughness 1.5 to 10 nm
 contact diameter ~ 10 nm, pressure ~ 10 GPa
 real contact area $\ll 10^{-3}$ (apparent contact area)

slide 9



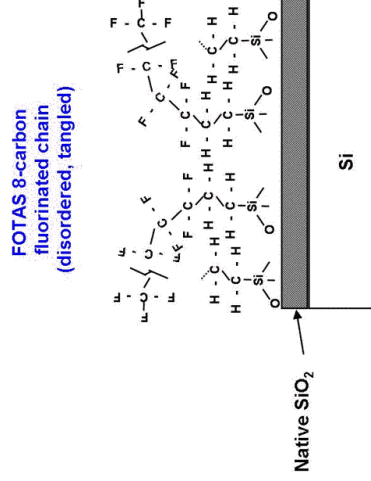
MEMS monolayer coupling agent

FOTAS (tridecafluoro-1,1,2,2-tetrahydrodecyltris(dimethylamino)silane)

vapor deposition

8 carbon chain

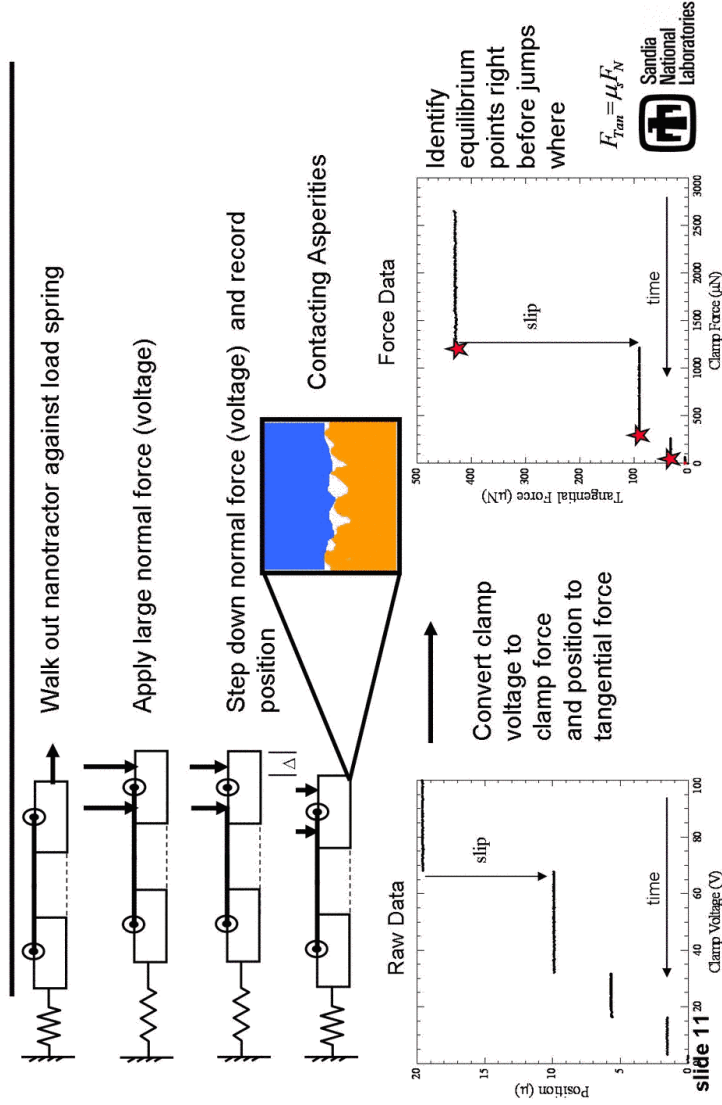
van der Waals forces not strong enough to self assemble (tangled)
 contact angle $\sim 110^\circ$



slide 10

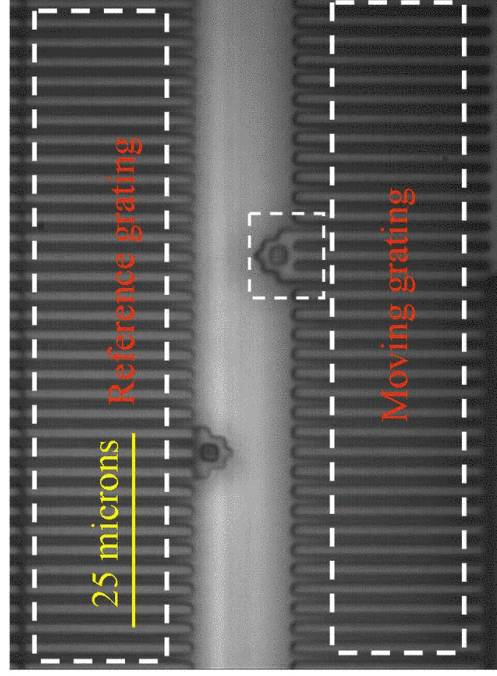


Static friction measurement

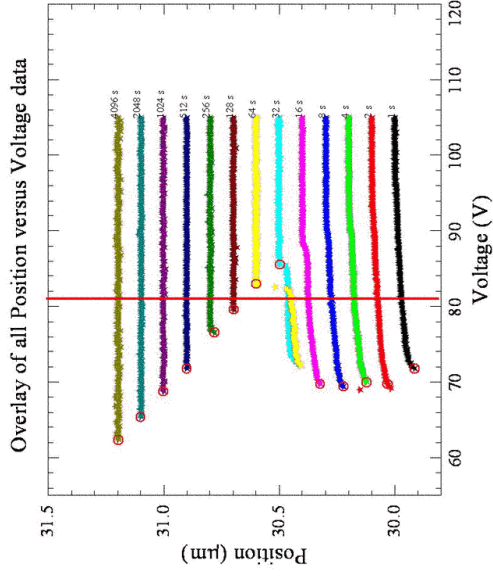


**Highly resolved slip measurements:
we measure position to 1 nm**

Use periodic grating and measure relative phase to 1 part in 2500



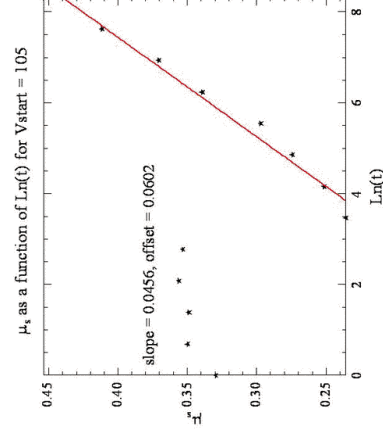
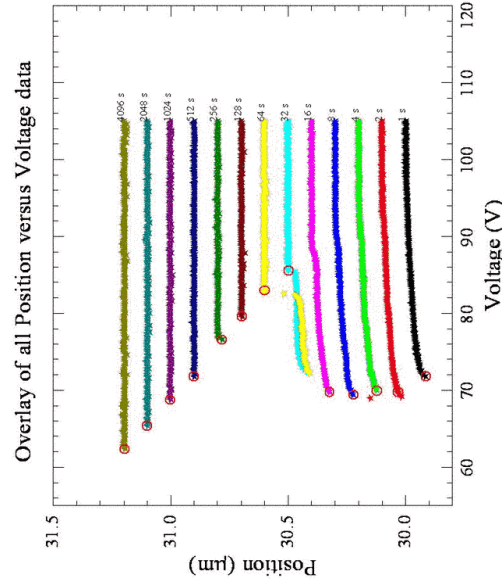
*As hold time increases, static friction increases.
For short hold times we get small-scale sliding.*



Jumps that occur above this critical voltage V_c (lower apparent friction) end up with sliding, while those released with voltage below it (higher apparent static friction) end up jumping



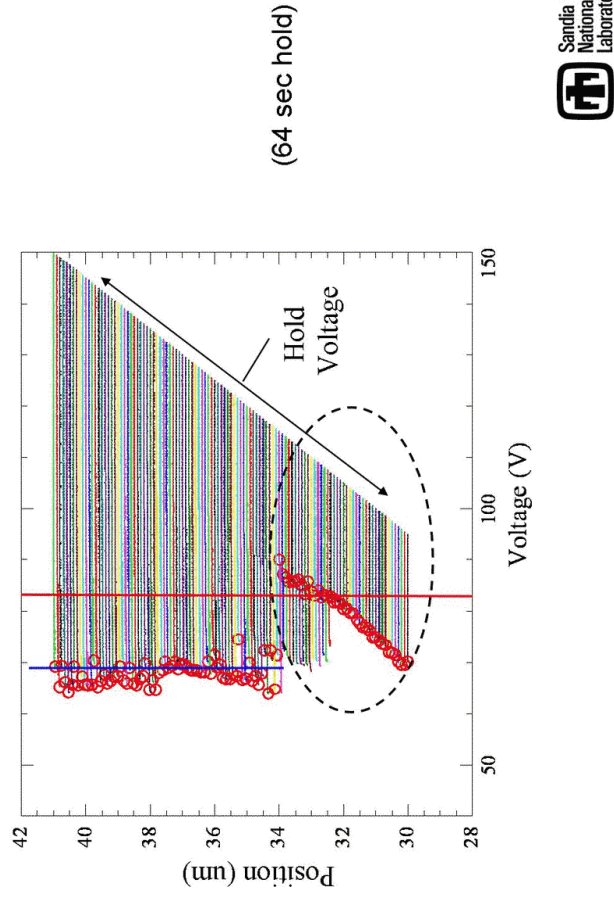
At longer hold times, we obtain a typical u_s time-dependence



From the plot on the left, we should only consider times of 32 seconds or longer as having well defined jumps

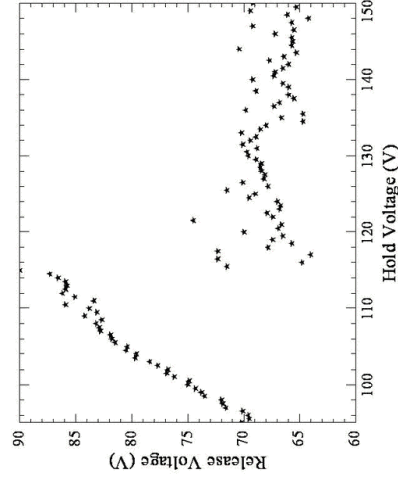
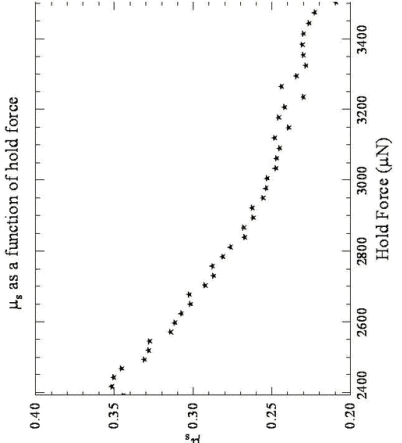


When we hold the clamp with a larger normal force, we experience a correspondingly lower friction force



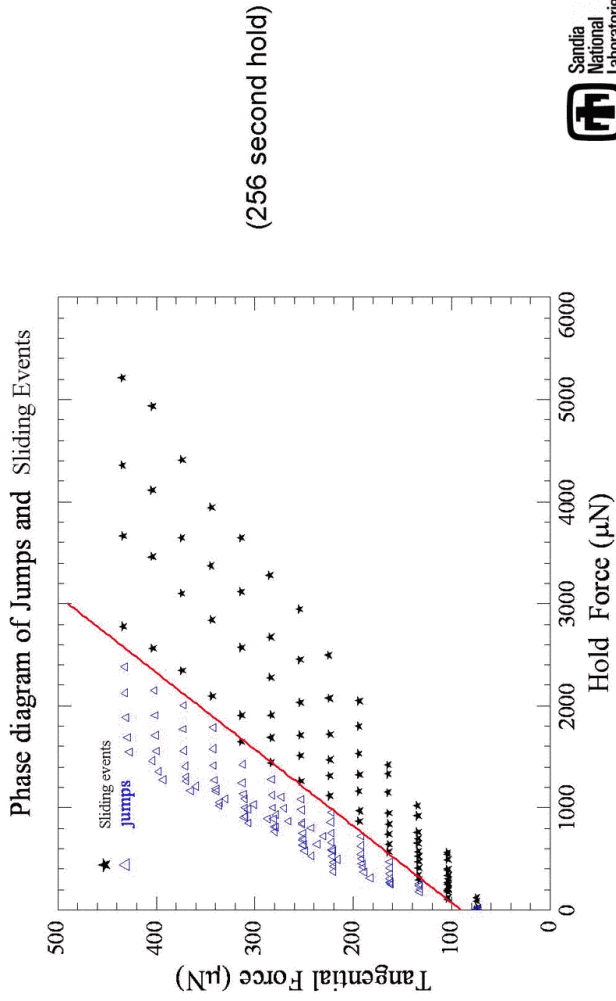
slide 15

u_s decreases with hold force



slide 16

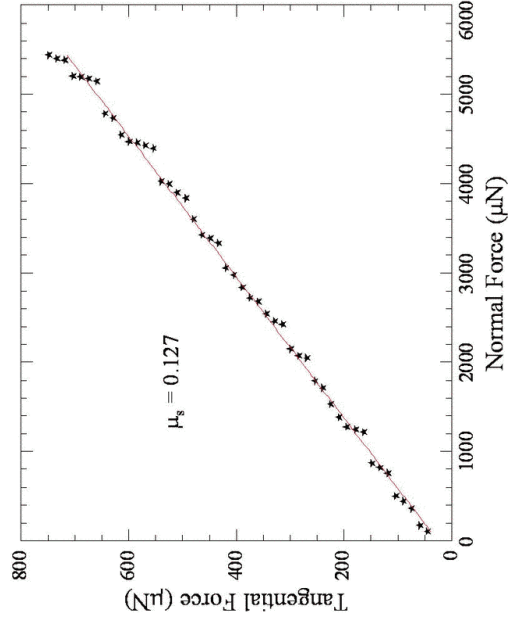
We observe a bifurcation in the jumps versus sliding events



slide 17



If we approach the static friction limit from "below", we get a low u_s (corresponding to short time)



slide 18



Summary of friction data

The nanotractor can be used to study friction of surface-micromachined interfaces

With FOTAS coating:

$$u_s(t) = \alpha + \beta \ln(t)$$

u_s decreases with increasing hold voltage (counter-intuitive)

If motion begins above (below) a certain critical voltage, sliding (a jump) is observed.

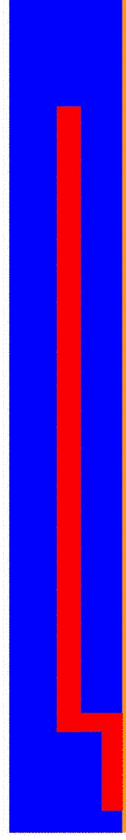
Phase space can be mapped out – this behavior occurs independent of tangential load



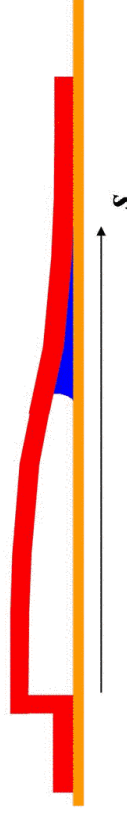
slide 19

Adhesion (e.g., “stiction”) is a big problem in micromachining

Initially free beam, but still in water

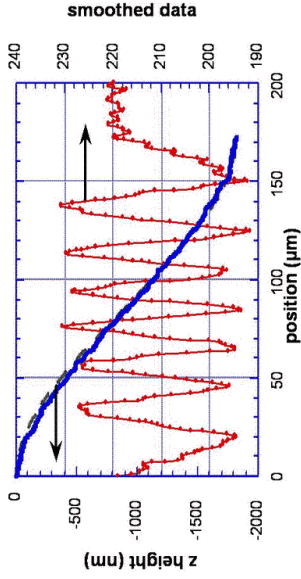
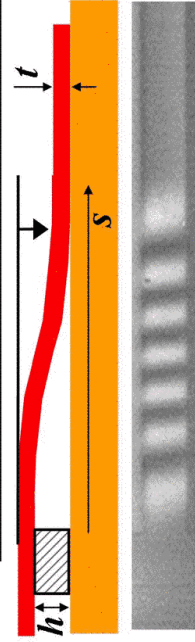


Drying leads to “stiction”



slide 20

We can use cantilevers to quantify the adhesion, Γ



Capillary adhesion can be avoided by critical point drying or by applying monolayer coatings

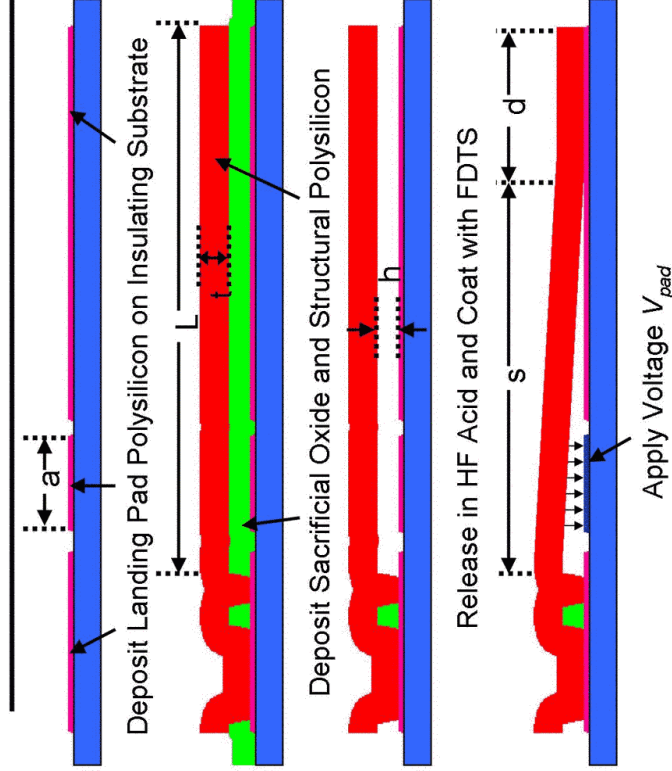
$$G = -\frac{dU_E}{wds} = \frac{3}{2} \frac{E h^2 t^3}{s^4} = \Gamma = 10 \frac{\text{mJ}}{\text{m}^2} \quad (\text{drying from water})$$

(de Boer and Michalske, Journal of Applied Physics, 1999)



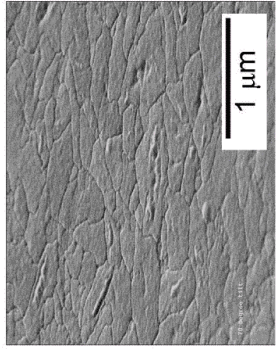
slide 21

Microcantilever process and test flow

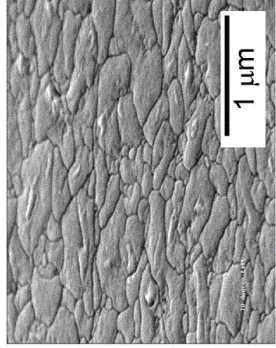


slide 22

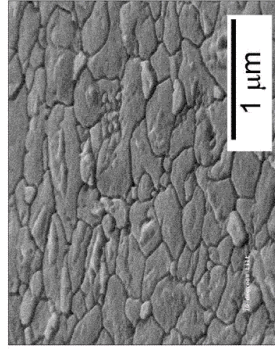
Oxidize the Poly 0 Surface to change surface roughness



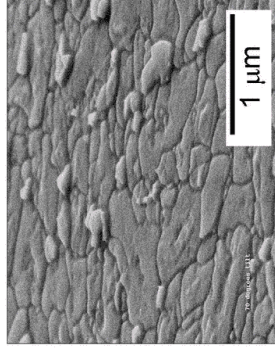
No oxidation, 2.6 nm rms



100 Å oxidation, 4.4 nm rms



300 Å oxidation, 5.6 nm rms



600 Å oxidation, 10.3 nm rms

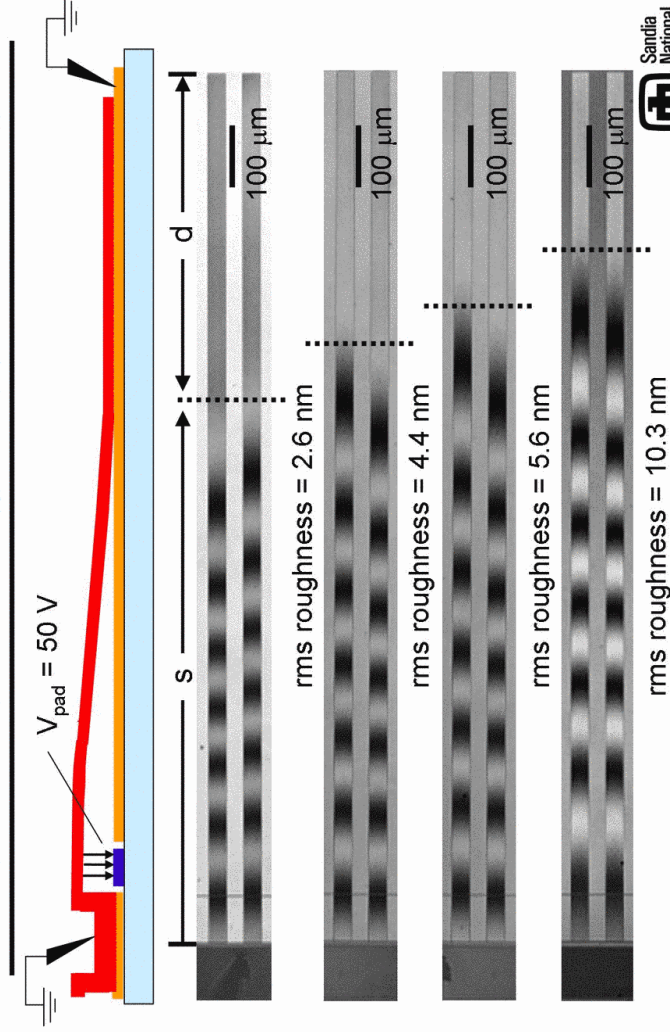
t (min)	tox (Å)	rms (nm)
0	--	2.6
20	100	4.4
136	300	5.6
400	600	10.3

Nanotexturing of the lower layer or polysilicon (P0) was accomplished via thermal oxidation in dry O₂ at 900° C for increasing times.



slide 23

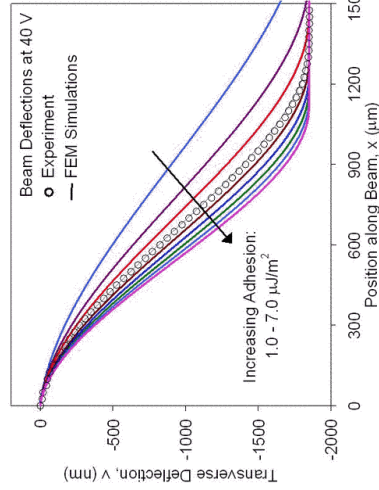
Interferograms show qualitative relationship between surface roughness and crack length



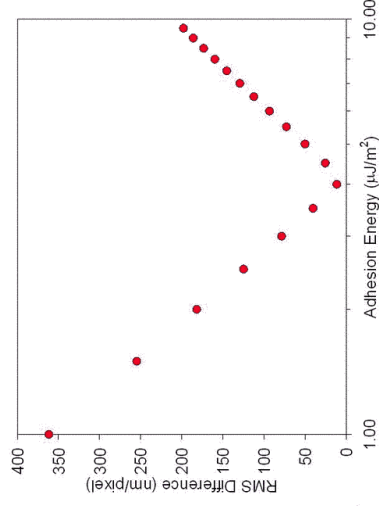
slide 24

Adhesion measurement with applied voltage

Finite element analysis (ABAQUS) and user subroutines were used to find beam profiles with surface adhesion, electrostatic loading and initial stress gradient.



The only free parameter in the models is the adhesion Γ .
 A least squares fit between the model and experiment was used to determine the value at each voltage.



(Knapp & de Boer, JMEMS, 2002)

slide 25

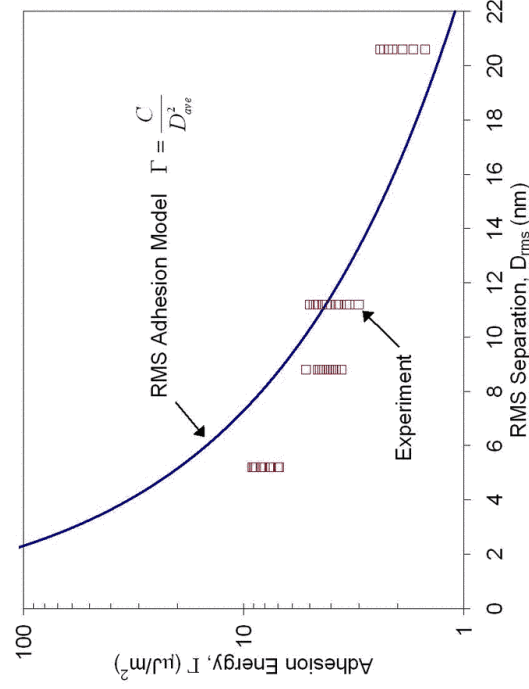
Experimental values of adhesion for each surface roughness

The measured values for adhesion loosely follow the approximation presented by Houston et al. (1996)

$$\Gamma = \frac{A}{12\pi D_{rms}^2}$$

These results raise the following questions:

1. What is the best way to characterize the separation between the two surfaces?
2. Do we have another method to determine if these results are *quantitatively* correct?



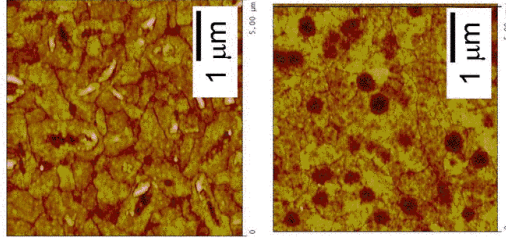
Atomic Force Microscopy Imaging with Force Displacement Numerical Analysis



slide 26

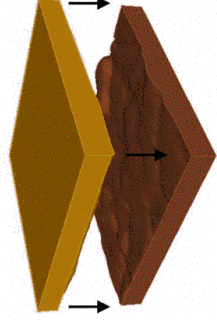
AFM topography data is analyzed using a numerical force-displacement routine

AFM Images



Numerical Force-Displacement Routine

1. Import AFM height data
2. Separate surfaces by initial displacement
3. Calculate surface heights entered into force displacement routine
4. Calculate force for each pixel
5. Find total force (sum)
6. Move surfaces towards each other
7. Repeat steps 3-6 to create attractive load-displacement curve



$$F_a = \frac{I_c^2}{N \text{ pixels}} \left[\sum_{\text{all pixels}} \frac{A g_f}{6\pi(d_{loc} + d_{co})^3} \right]$$

Anandarajah and Chen 1995



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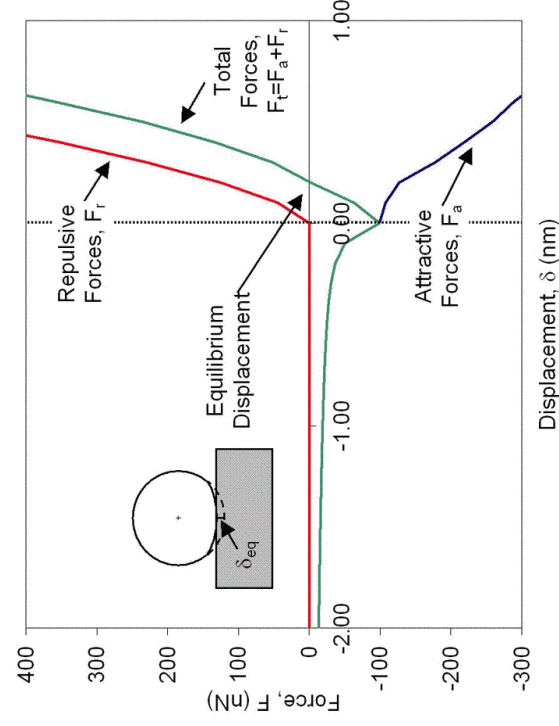
Calculate the total force-displacement curve using the AFM analysis and Hertzian mechanics

Attractive force-displacement curve based on AFM analysis

Repulsive force-displacement curve based on Hertzian mechanics

$$F_r = \frac{2}{3} \left(\frac{E}{1-\nu^2} \right) \sqrt{R\delta^3}$$

DMT Adhesion Model



Calculate adhesion energy by evaluating the area under the total force-displacement curve from the equilibrium displacement to infinity.

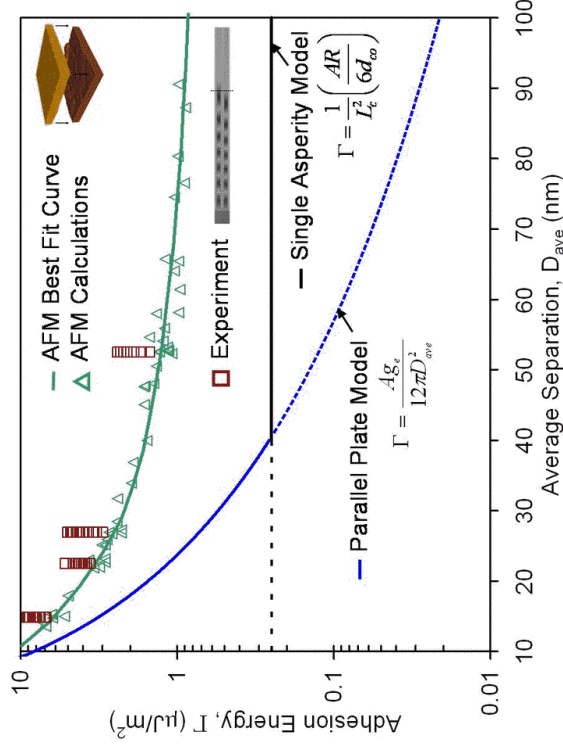
slide 28



Predicted values of adhesion with AFM data

We placed the surfaces together in the following combinations for each roughness:

- Poly 0 and Poly 0
- Poly 0 and Poly 2



The average surface separation D_{ave} is calculated for each AFM pair according to

$$D_{ave} = \frac{1}{N} \left[\sum_{all\ pixels} d_{loc} \right]$$

Delrio, de Boer et al., Nat. Mat. (2005)

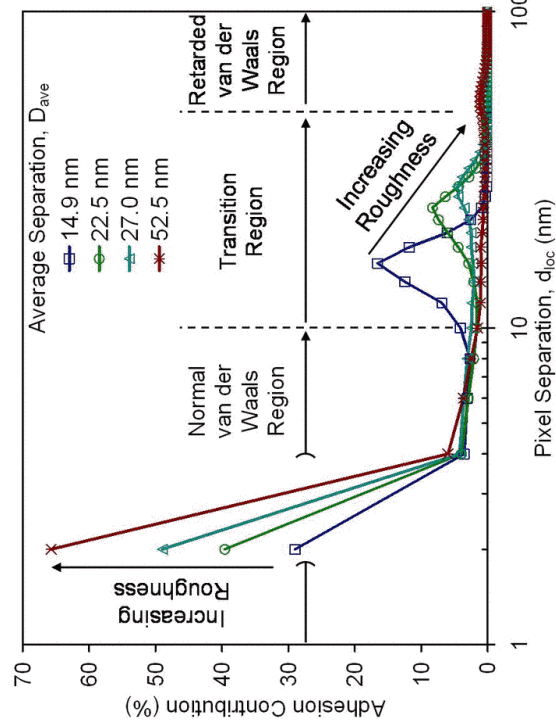


slide 29

Histogram of adhesion contributions vs. pixel separation

Smoothest Surface
Adhesion contribution from both contacting asperities and non-contacting areas (combination of two extreme adhesion models).

Roughest Surface
Adhesion contribution mainly from contacting asperity (converging to Fuller-Tabor/Maugis model for single asperity).



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Summary - dry adhesion in MEMS

Microcantilevers are used to measure adhesion in MEMS

Adhesion is in the $\mu\text{J}/\text{m}^2$ range

For low surface roughness, adhesion dominated by retarded van der Waals forces

For higher surface roughnesses, adhesion dominated by normal van der Waals forces

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